TOSHIBA Photocoupler IRED & Photo-IC

# **TLP251**

Inverter For Air Conditioner **Induction Heating Transistor Inverter** Power MOS FET Gate Drive **IGBT Gate Drive** 

The TOSHIBA TLP251 consists of an infrared emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP251 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP251 is capable of "direct" gate drive of lower power IGBTs. ( to 15A)

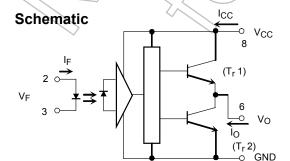
- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (VCC): 10-35V
- Output current (IO): ±0.4A(max.)
- Switching time (t<sub>pLH</sub> / t<sub>pHL</sub>): 1µs(max.)
- Isolation voltage: 2500Vrms(min.)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-Approved: EN 60747-5-5 (Note 1)

Note 1:When a VDE approved type is needed, please designate the Option(D4).

#### **Truth Table** Tr2 On Input On Off

Off

LED

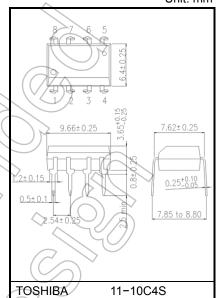


Off

On

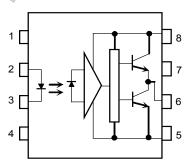
A 0.1µF bypass capcitor must be connected between pin 8 and 5(see Note 5).

Unit: mm



Weight: 0.54 g (typ.)

### Pin Configuration (top view)



1: N.C. 5 : GND 6: VO (Output) 2 : Anode 3: Cathode 7: N.C. 4: N.C. 8: V<sub>CC</sub>

Start of commercial production 1992-01

### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
LED	Forward current	lF	20	mA	
	Forward current derating	(Ta ≥ 70°C)	Δl <sub>F</sub> / ΔTa	- 0.36	mA /°C
	Peak transient forward current	(Note 1)	IFPT	1	A
	Reverse voltage		VR	5	V
	Diode power dissipation		PD	40 _	(mW/<
	Diode power dissipation deration	ΔPD/°C	-0.72	mW/°C	
	Junction temperature	Tj	125	လို	
	"H" peak output current (Pw ≤ 2.0μs, f ≤ 15kHz)	(Note 2)	Іорн	-0.4	A >
	"L" peak output current (P <sub>W</sub> ≤ 2.0μs, f ≤ 15kHz)	(Note 2)	I <sub>OPL</sub>	0.4	A
	0	(Ta ≤ 70°C)	v (	35	\ \ \ \ \
	Output voltage	(Ta = 85°C)	Vo	24	V
jo		(Ta ≤ 70°C)		35	(0)
Detector	Supply voltage	(Ta = 85°C)	Vce	24	
ă	Output voltage derating (Ta ≥ 70°C)		ΔV <sub>O</sub> / ΔΤα	-0.73	VVC
	Supply voltage derating (Ta ≥ 70°C)		ΔV <sub>CC</sub> / ΔΤα	-0.73	V/°C
	Output Power dissipation		Po	800	mW
	Output Power dissipation derat	ting (Ta ≥70°C )	ΔP <sub>O</sub> /°C	-14.5	mW/°C
	Junction temperature		Tj 🦙	125	°C
Opera	ating frequency	f	25	kHz	
Opera	ating temperature range	Topr	−20 to 85	°C	
Stora	ge temperature range	Tstg	−55 to 125	°C	
Lead	soldering temperature(10 s)	T <sub>sol</sub>	260	°C	
Isolat	tion voltage (AC, 60 s.,R.H.≤ 60	BVs	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width  $P_W \le 1 \mu s$ , 300 pps

Note 2: Expornential waveform

Note 3: Expornential waveform,  $I_{OPH} \le -0.25 \text{ A} (\le 2.0 \text{ } \mu\text{s}), I_{OPL} \le +0.25 \text{ A} (\le 2.0 \text{ } \mu\text{s})$ 

Note 4: Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.



### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit	
Input current, on	(Note 1)	I <sub>F(ON)</sub>	7	8	10	mA
Input voltage, off		V <sub>F</sub> (OFF)	0	_	0.8	V
Supply voltage		Vcc	10	_	30	⟨v
Peak output current		I <sub>OPH</sub> / I <sub>OPL</sub>	_	_	±0.1	A
Operating temperature		T <sub>opr</sub>	-20	25	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Input signal rise time(fall time)<0.5 μs.

### Electrical Characteristics (Ta = -20 to 70°C, unless otherwise specified)

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.*	Max.	Unit	
Input forward voltage		VF	_	I <sub>F</sub> = 10 mA , Ta = 25 °C		1.6	1.8	V	
Temperature coefficient of forward voltage		ΔV <sub>F</sub> / ΔTa	-(	JE=10 mA		-2.0	_	mV / °C	
Input reverse current		IR	$\mathcal{A}$	V <sub>R</sub> = 5 V, Ta = 25 °C	<i>リー</i>	_	10	μΑ	
Input capacitance	Ст	7	V = 0 V , f = 1 MHz , Ta = 25 °C	_	45	250	pF		
Output current	"H" level	Іорн	1)	V <sub>CC</sub> =30 V	-0.1	-0.25	_		
Output current	"L" level	(IOPL	2	(Note 1) I <sub>F</sub> =0 mA V <sub>6</sub> -5 = 2.5 V	0.1	0.2	_	Α	
O to to the se	"H" level	Уон	3	$V_{CC1} = +15 \text{ V}, V_{EE1} = -15 \text{ V}$ RL = 200 $\Omega$ , I <sub>E</sub> = 5 mA	11	13.2	_	V	
Output voltage	"L" level	V <sub>OL</sub>	4	$V_{CC1}$ = +15 V, $V_{EE1}$ = -15 V RL = 200 $\Omega$ , $V_F$ = 0.8 V	_	-14.5	-12.5	V	
	"H" level	Іссн	_	V <sub>CC</sub> = 30 V, I <sub>F</sub> = 10 mA Ta = 25 °C	_	7.5	_		
	~			V <sub>CC</sub> = 30 V, I <sub>F</sub> = 10 mA	_	_	11	^	
Supply current	"L" level	Ject	_	V <sub>CC</sub> = 30 V, I <sub>F</sub> = 0 mA Ta = 25 °C	_	8	_	· mA	
				V <sub>CC</sub> = 30 V, I <sub>F</sub> = 0 mA	_	_	11	1	
Threshould input current	"Output L → H"	IFLH	<del>-</del>	V <sub>CC1</sub> = +15 V, V <sub>EE1</sub> = -15 V R <sub>L</sub> = 200 Ω, V <sub>O</sub> > 0 V	_	1.2	5	mA	
Threshold input voltage	"Output H → L"	V <sub>FHL</sub>	_	V <sub>CC1</sub> = +15 V, V <sub>EE1</sub> = -15 V R <sub>L</sub> = 200 Ω, V <sub>O</sub> < 0 V	0.8	_	_	V	
Supply voltage	Supply voltage				10	_	35	V	
Capacitance (input-output)	Cs	_	Vs = 0 V , f = 1 MHz Ta = 25° C	_	1.0	2.0	pF		
Resistance (input-outp	Rs	_	Vs = 500 V, Ta = 25 °C R.H. ≤ 60 %	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω		

Note : All typical values are at Ta = 25 °C

Note 1: Duration of IO time  $\leq$  50  $\mu$ s

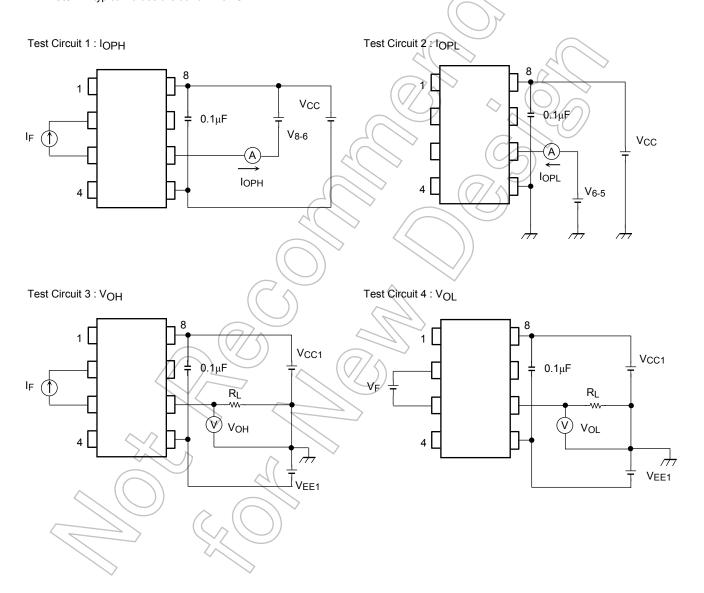
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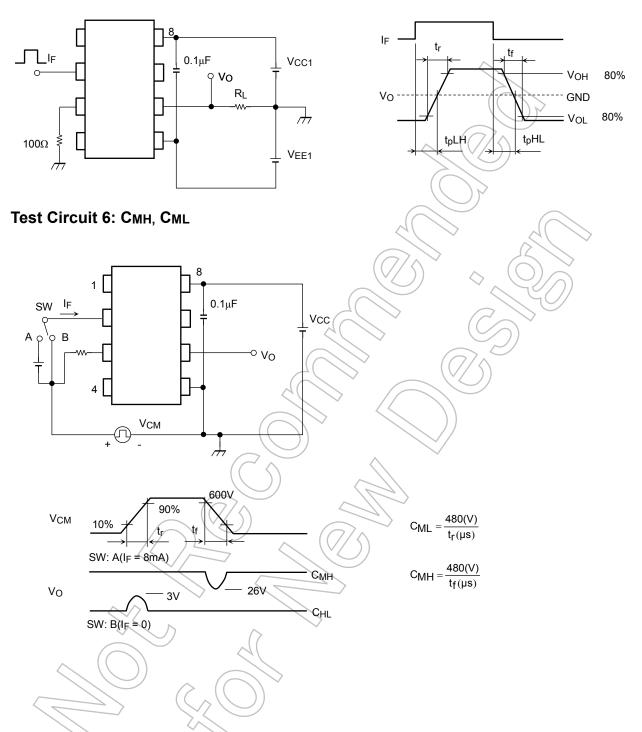
# Switching Characteristics (Ta = −20 to 70°C, unless otherwise specified)

Characteristic		Symbol	Test Cir- cuit	Test Condition	Min.	Typ.*	Max.	Unit
Propagation	L→H	t <sub>pLH</sub>		IF = 8 mA	_	0.25	1.0	μs
delay time	H→L	tpHL	5	$V_{CC1}$ = +15 V, $V_{EE1}$ = -15 V $R_L$ = 200 $Ω$	_	0.25	1.0	
Common mode transient immunity at high level output  Common mode transient immunity at low level output		Смн	- 6	V <sub>CM</sub> = 600 V, I <sub>F</sub> = 8 mA, V <sub>CC</sub> = 30 V, Ta = 25 °C	-5000	/_	_	V / μs
		C <sub>ML</sub>		V <sub>CM</sub> = 600 V, I <sub>F</sub> = 0 mA, V <sub>CC</sub> = 30 V, Ta = 25 °C	5000	<u> </u>	_	V / μs

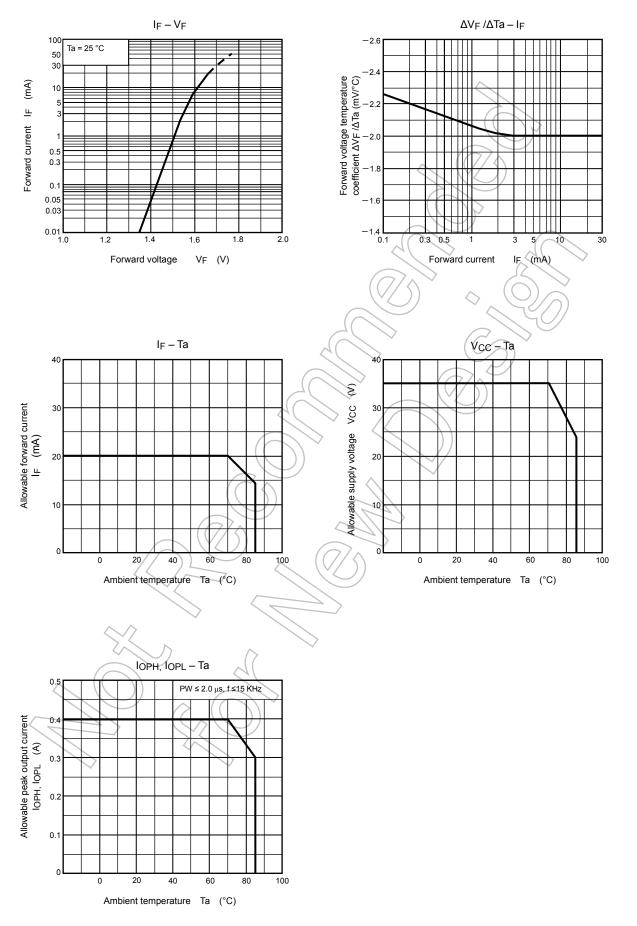
Note: All typical values are at Ta = 25 °C



### Test Circuit 5: tpLH, tpHL, tr, tf



C<sub>ML</sub> (C<sub>MH</sub>) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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